

Please add the following new claims:

Sub E1

12 (New) An organic electroluminescence display device comprising:
a resin substrate; and
an insulating film comprising a nitride on the resin substrate.

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13 (New) The organic electroluminescence display device according to claim 12 wherein
said resin substrate comprises polyethylene terephthalate.

14 (New) The organic electroluminescence display device according to claim 12 wherein
said insulating film comprises a material selected from the group consisting of silicon nitride and
silicon oxy-nitride.

Sub E2

15 (New) An organic electroluminescence display device comprising:
a resin substrate; and
an underlying insulating film formed on the resin substrate,
wherein the underlying insulating film comprises a first insulating film comprising
a nitride and a second insulating film comprising silicon oxide.

16 (New) The organic electroluminescence display device according to claim 15 wherein
said resin substrate comprises polyethylene terephthalate.

17 (New) The organic electroluminescence display device according to claim 15 wherein said first insulating film comprises a material selected from the group consisting of silicon nitride and silicon oxy-nitride.

18 (New) An organic electroluminescence display device comprising:
a resin substrate;
an insulating film comprising a nitride on the resin substrate; and
a thin film transistor formed over the insulating film.

19 (New) The organic electroluminescence display device according to claim 18 wherein said resin substrate comprises polyethylene terephthalate.

20 (New) The organic electroluminescence display device according to claim 18 wherein said insulating film comprises a material selected from the group consisting of silicon nitride and silicon oxy-nitride.

21 (New) An organic electroluminescence display device comprising:
a resin substrate;
an underlying insulating film formed on the resin substrate; and
a thin film transistor formed over the underlying insulating film,
wherein the underlying insulating film comprises a first insulating film comprising a nitride and a second insulating film comprising silicon oxide.

22(New) The organic electroluminescence display device according to claim 22 wherein said resin substrate comprises polyethylene terephthalate.

23(New) The organic electroluminescence display device according to claim 22 wherein said first insulating film comprises a material selected from the group consisting of silicon nitride and silicon oxy-nitride.

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24(New) An organic electroluminescence display device comprising:
a resin substrate;
an insulating film comprising a nitride on the resin substrate; and
a channel region of a thin film transistor, wherein the channel region comprises amorphous silicon and is formed over the insulating film.

25(New) The organic electroluminescence display device according to claim 24 wherein said resin substrate comprises polyethylene terephthalate.

26(New) The organic electroluminescence display device according to claim 24 wherein said insulating film comprises a material selected from the group consisting of silicon nitride and silicon oxy-nitride.

27 (New) An organic electroluminescence display device comprising:
a resin substrate;
an underlying insulating film formed on the resin substrate; and

a channel region of a thin film transistor formed over the underlying insulating film,
said channel region comprising amorphous silicon,

wherein the underlying insulating film comprises a first insulating film comprising
a nitride and a second insulating film comprising silicon oxide.

28 (New) The organic electroluminescence display device according to claim 27 wherein
said resin substrate comprises polyethylene terephthalate.

Sub #4
29 (New) The organic electroluminescence display device according to claim 27 wherein
said insulating film comprises a material selected from the group consisting of silicon nitride and
silicon oxy-nitride.

30 (New) An organic electroluminescence display device comprising:
a resin substrate;
an insulating film comprising a nitride on the resin substrate; and
a channel region of a thin film transistor, wherein the channel region comprises
crystalline silicon and is formed over the insulating film.

31 (New) The organic electroluminescence display device according to claim 30 wherein
said resin substrate comprises polyethylene terephthalate.

32 (New) The organic electroluminescence display device according to claim 30 wherein
said insulating film comprises a material selected from the group consisting of silicon nitride and
silicon oxy-nitride.